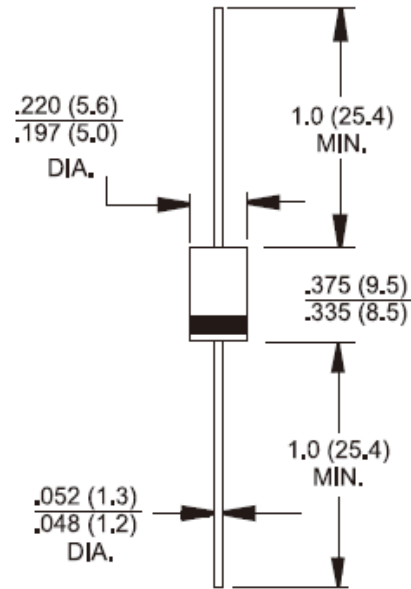


DO-201AD



Dimensions in inches and (millimeters)

Marking Diagram



SF6XG = Specific Device Code
G = Green Compound
Y = Year
WW = Work Week

Features

- ✧ High efficiency, low VF
- ✧ High current capability
- ✧ High reliability
- ✧ High surge current capability
- ✧ Low power loss
- ✧ For use in low voltage, high frequency inverter, free wheeling, and polarity protection application
- ✧ Green compound with suffix "G" on packing code & prefix "G" on datecode.

Mechanical Data

- ✧ Case: Molded plastic
- ✧ Epoxy: UL 94V-0 rate flame retardant
- ✧ Lead: Pure tin plated, lead free, solderable per MIL-STD-202, Method 208 guaranteed
- ✧ Polarity: Color band denotes cathode
- ✧ High temperature soldering guaranteed: 260°C/10 seconds/.375", (9.5mm) lead lengths at 5 lbs., (2.3kg) tension
- ✧ Mounting position: Any
- ✧ Weight: 1.2 grams

Maximum Ratings and Electrical Characteristics

Rating at 25 °C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%

Type Number	Symbol	SF 61G	SF 62G	SF 63G	SF 64G	SF 65G	SF 66G	SF 67G	SF 68G	Units
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	50	100	150	200	300	400	500	600	V
Maximum RMS Voltage	V_{RMS}	35	70	105	140	210	280	350	420	V
Maximum DC Blocking Voltage	V_{DC}	50	100	150	200	300	400	500	600	V
Maximum Average Forward Rectified Current .375 (9.5mm) Lead Length @ $T_A = 55^\circ C$	$I_{F(AV)}$	6								A
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I_{FSM}	150								A
Maximum Instantaneous Forward Voltage (Note 1) @ 6 A	V_F	0.975			1.3		1.7			V
Maximum DC Reverse Current at Rated DC Blocking Voltage $T_A = 25^\circ C$ $T_A = 125^\circ C$	I_R	5				100				uA uA
Maximum Reverse Recovery Time (Note 2)	T_{rr}	35								nS
Typical Junction Capacitance (Note 3)	C_j	100				50				pF
Typical Thermal Resistance (Note 4)	$R_{\theta JA}$ $R_{\theta JL}$	40				5				$^\circ C/W$
Operating Temperature Range	T_J	- 65 to + 150								$^\circ C$
Storage Temperature Range	T_{STG}	- 65 to + 150								$^\circ C$

Note 1: Pulse Test with PW=300 usec, 1% Duty Cycle

Note 2: Reverse Recovery Test Conditions: $I_F=0.5A$, $I_R=1.0A$, $I_{RR}=0.25A$

Note 3: Measured at 1 MHz and Applied Reverse Voltage of 4.0V D.C.

Note 4: Mount on Cu-Pad Size 16mm x 16mm on PCB.

RATINGS AND CHARACTERISTIC CURVES (SF61G THRU SF68G)

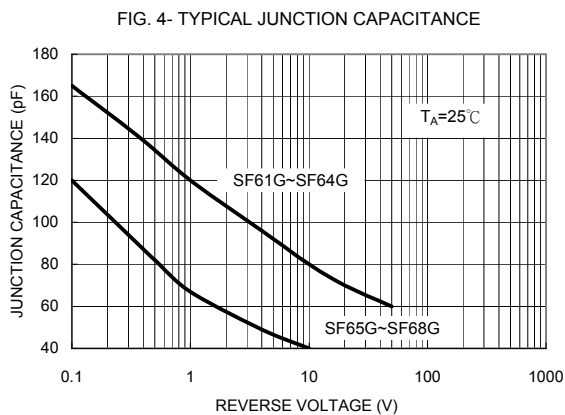
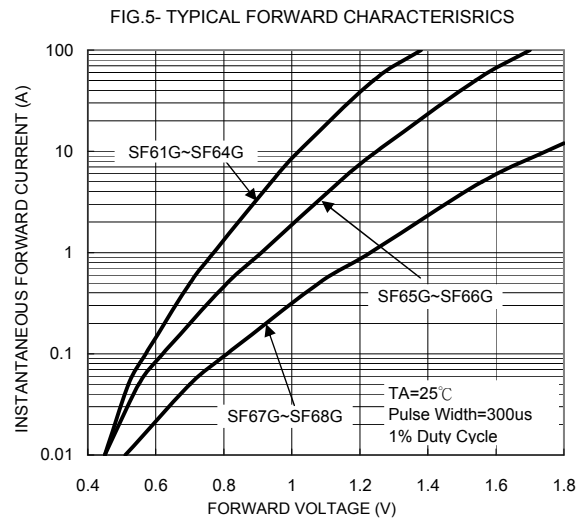
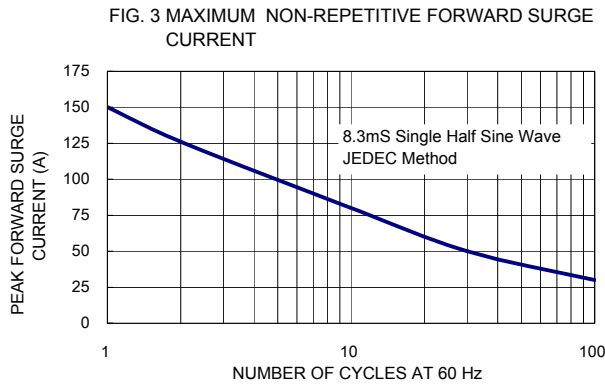
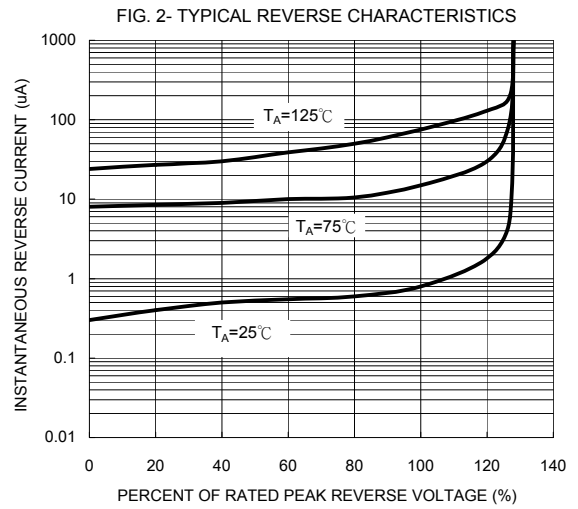
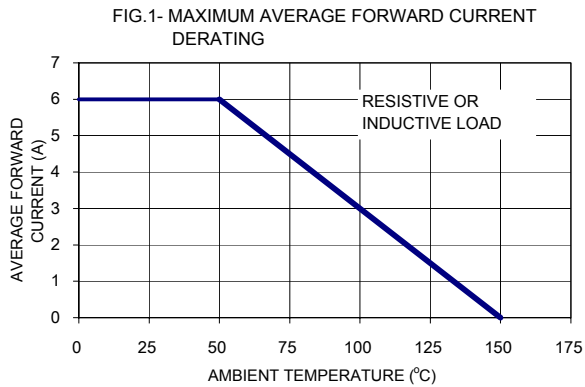


FIG. 6- REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM

